## Noninverting 3-State Buffer MC74VHC1G125, MC74VHC1GT125

The MC74VHC1G125 / MC74VHC1GT125 is a single non-inverting 3 -state buffer in tiny footprint packages. The MC74VHC1G125 has CMOS-level input thresholds while the MC74VHC1GT125 has TTL-level input thresholds.

The internal circuit is composed of three stages, including a buffered 3-state output which provides high noise immunity and stable output.

The input structures provide protection when voltages up to 5.5 V are applied, regardless of the supply voltage. This allows the device to be used to interface 5 V circuits to 3 V circuits. The output structures also provide protection when $\mathrm{V}_{\mathrm{CC}}=0 \mathrm{~V}$ and when the output voltage exceeds $\mathrm{V}_{\mathrm{CC}}$. These input and output structures help prevent device destruction caused by supply voltage - input/output voltage mismatch, battery backup, hot insertion, etc.

## Features

- Designed for 2.0 V to $5.5 \mathrm{~V} \mathrm{~V}_{\mathrm{CC}}$ Operation
- $3.5 \mathrm{~ns} \mathrm{t}_{\mathrm{PD}}$ at 5 V (typ)
- Inputs/Outputs Over-Voltage Tolerant up to 5.5 V
- I IOFF Supports Partial Power Down Protection
- Source/Sink 8 mA at 3.0 V
- Available in SC-88A, SC-74A, TSOP-5, SOT-953 and UDFN6 Packages
- Chip Complexity < 100 FETs
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are $\mathrm{Pb}-$ Free, Halogen Free/BFR Free and are RoHS Compliant


Figure 1. Logic Symbol

MARKING DIAGRAMS


SOT-953
P5 SUFFIX
CASE 527AE


TSOP-5
DT SUFFIX
CASE 483


DBV SUFFIX CASE 318BQ
SC-88A DF SUFFIX
CASE 419A


UDFN6
$1.2 \times 1.0$
CASE 517AA


$$
\begin{array}{ll}
\text { XX } & =\text { Specific Device Code } \\
\text { M } & =\text { Date Code* } \\
\text { - } & =\text { Pb-Free Package }
\end{array}
$$

(Note: Microdot may be in either location)
*Date Code orientation and/or position may vary depending upon manufacturing location.

See detailed ordering, marking and shipping information in the package dimensions section on page 8 of this data sheet.

## MC74VHC1G125, MC74VHC1GT125


(SC-88A / TSOP-5 / SC-74A)


Figure 2. Pinout (Top View)

PIN ASSIGNMENT
(SC-88A / TSOP-5 / SC-74A)

| Pin | Function |
| :---: | :---: |
| 1 | $\overline{\mathrm{OE}}$ |
| 2 | A |
| 3 | GND |
| 4 | Y |
| 5 | $\mathrm{~V}_{\mathrm{CC}}$ |

PIN ASSIGNMENT (SOT-953)

| Pin | Function |
| :---: | :---: |
| 1 | A |
| 2 | GND |
| 3 | $\overline{\mathrm{OE}}$ |
| 4 | Y |
| 5 | $\mathrm{~V}_{\mathrm{CC}}$ |

PIN ASSIGNMENT (UDFN)

| Pin | Function |
| :---: | :---: |
| 1 | OE |
| 2 | A |
| 3 | GND |
| 4 | Y |
| 5 | NC |
| 6 | $\mathrm{~V}_{\mathrm{CC}}$ |

FUNCTION TABLE

| Input |  | Output |
| :---: | :---: | :---: |
| $\mathbf{O E}$ | A | $\mathbf{Y}$ |
| L | L | L |
| L | H | H |
| H | X | Z |

X = Don't Care

## MC74VHC1G125, MC74VHC1GT125

MAXIMUM RATINGS

| Symbol | Characteristics |  | Value | Unit |
| :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{CC}}$ | DC Supply Voltage | TSOP-5, SC-88A (NLV) <br> SC-74A, SC-88A, UDFN6, SOT-953 | $\begin{aligned} & -0.5 \text { to }+7.0 \\ & -0.5 \text { to }+6.5 \end{aligned}$ | V |
| $\mathrm{V}_{\text {IN }}$ | DC Input Voltage | TSOP-5, SC-88A (NLV) <br> SC-74A, SC-88A, UDFN6, SOT-953 | $\begin{aligned} & -0.5 \text { to }+7.0 \\ & -0.5 \text { to }+6.5 \end{aligned}$ | V |
| V OUT | DC Output Voltage TSOP-5, SC-88A (NLV) | Active-Mode (High or Low State) Tri-State Mode (Note 1) Power-Down Mode ( $\mathrm{V}_{\mathrm{CC}}=0 \mathrm{~V}$ ) | $\begin{gathered} -0.5 \text { to } V_{\mathrm{cc}}+0.5 \\ -0.5 \text { to }+7.0 \\ -0.5 \text { to }+7.0 \end{gathered}$ | V |
|  | DC Output Voltage SC-74A, SC-88A, UDFN6, SOT-953 | Active-Mode (High or Low State) <br> Tri-State Mode (Note 1) <br> Power-Down Mode $\left(\mathrm{V}_{\mathrm{CC}}=0 \mathrm{~V}\right)$ | $\begin{gathered} -0.5 \text { to } \mathrm{V}_{\mathrm{cc}}+0.5 \\ -0.5 \text { to }+6.5 \\ -0.5 \text { to }+6.5 \end{gathered}$ | V |
| $\mathrm{IIK}^{\text {K }}$ | DC Input Diode Current | $\mathrm{V}_{\mathrm{IN}}<$ GND | -20 | mA |
| lok | DC Output Diode Current | $\mathrm{V}_{\text {OUT }}$ < GND | -20 | mA |
| IOUT | DC Output Source/Sink Current |  | $\pm 25$ | mA |
| $\mathrm{I}_{\text {CC }}$ or $\mathrm{I}_{\text {GND }}$ | DC Supply Current per Supply Pin or Ground Pin |  | $\pm 50$ | mA |
| $\mathrm{T}_{\text {STG }}$ | Storage Temperature Range |  | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{L}}$ | Lead Temperature, 1 mm from Case for 10 secs |  | 260 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{J}$ | Junction Temperature Under Bias |  | +150 | ${ }^{\circ} \mathrm{C}$ |
| $\theta_{\mathrm{JA}}$ | Thermal Resistance (Note 2) | $\begin{array}{r} \text { SC-88A } \\ \text { SC-74A } \\ \text { SOT-953 } \\ \text { UDFN6 } \end{array}$ | $\begin{aligned} & 377 \\ & 320 \\ & 254 \\ & 154 \end{aligned}$ | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $P_{\text {D }}$ | Power Dissipation in Still Air | $\begin{array}{r} \text { SC-88A } \\ \text { SC-74A } \\ \text { SOT-953 } \\ \text { UDFN6 } \end{array}$ | $\begin{aligned} & 332 \\ & 390 \\ & 491 \\ & 812 \end{aligned}$ | mW |
| MSL | Moisture Sensitivity |  | Level 1 | - |
| $\mathrm{F}_{\mathrm{R}}$ | Flammability Rating | Oxygen Index: 28 to 34 | UL 94 V-0 @ 0.125 in | - |
| $\mathrm{V}_{\text {ESD }}$ | ESD Withstand Voltage (Note 3) | Human Body Model Charged Device Model | $\begin{aligned} & 2000 \\ & 1000 \end{aligned}$ | V |
| ILatchup | Latchup Performance (Note 4) |  | $\pm 100$ | mA |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Applicable to devices with outputs that may be tri-stated.
2. Measured with minimum pad spacing on an FR4 board, using 10mm-by-1inch, 2 ounce copper trace no air flow per JESD51-7.
3. HBM tested to ANSI/ESDA/JEDEC JS-001-2017. CDM tested to EIA/JESD22-C101-F. JEDEC recommends that ESD qualification to EIA/JESD22-A115-A (Machine Model) be discontinued per JEDEC/JEP172A.
4. Tested to EIA/JESD78 Class II.

## MC74VHC1G125, MC74VHC1GT125

RECOMMENDED OPERATING CONDITIONS

| Symbol | Characteristics |  | Min | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{CC}}$ | Positive DC Supply Voltage |  | 2.0 | 5.5 | V |
| $\mathrm{V}_{\text {IN }}$ | DC Input Voltage |  | 0 | 5.5 | V |
| $\mathrm{V}_{\text {OUT }}$ | DC Output Voltage | TSOP-5, SC-88A (NLV) | 0 | $\mathrm{V}_{\mathrm{CC}}$ | V |
|  | DC Output Voltage | SC-74A, SC-88A, UDFN6, SOT-953 <br> Active-Mode (High or Low State) <br> Tri-State Mode (Note 1) <br> Power-Down Mode $\left(\mathrm{V}_{\mathrm{cc}}=0 \mathrm{~V}\right)$ | $\begin{aligned} & 0 \\ & 0 \\ & 0 \end{aligned}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{cc}} \\ & 5.5 \\ & 5.5 \end{aligned}$ |  |
| $\mathrm{T}_{\mathrm{A}}$ | Operating Temperature Range |  | -55 | +125 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{t}_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}}$ | Input Rise and Fall Time | $\begin{array}{r} \text { TSOP-5, SC-88A (NLV) } \\ \mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V} \text { to } 3.6 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \end{array}$ | $\begin{aligned} & 0 \\ & 0 \end{aligned}$ | $\begin{gathered} 100 \\ 20 \end{gathered}$ | $\mathrm{ns} / \mathrm{V}$ |
|  | Input Rise and Fall Time | $\begin{array}{r} \text { SC-74A, SC-88A, UDFN6, SOT- } 953 \\ \mathrm{~V} \mathrm{VC}=2.0 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{CC}}=2.3 \mathrm{~V} \text { to } 2.7 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{CC}}=3.0 \mathrm{~V} \text { to } 3.6 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \\ \hline \end{array}$ | $\begin{aligned} & 0 \\ & 0 \\ & 0 \\ & 0 \end{aligned}$ | $\begin{gathered} 20 \\ 20 \\ 10 \\ 5 \\ \hline \end{gathered}$ |  |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS (MC74VHC1G125)

| Symbol | Parameter | Test Conditions | $\mathrm{V}_{\mathrm{cc}}$ <br> (V) | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  |  | $-40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq 85^{\circ} \mathrm{C}$ |  | $-55^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq 125^{\circ} \mathrm{C}$ |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | Min | Typ | Max | Min | Max | Min | Max |  |
| $\mathrm{V}_{\mathrm{IH}}$ | High-Level Input Voltage |  | 2.0 | 1.5 | - | - | 1.5 | - | 1.5 | - | V |
|  |  |  | 3.0 | 2.1 | - | - | 2.1 | - | 2.1 | - |  |
|  |  |  | 4.5 | 3.15 | - | - | 3.15 | - | 3.15 | - |  |
|  |  |  | 5.5 | 3.85 | - | - | 3.85 | - | 3.85 | - |  |
| $\mathrm{V}_{\mathrm{IL}}$ | Low-Level Input Voltage |  | 2.0 | - | - | 0.5 | - | 0.5 | - | 0.5 | V |
|  |  |  | 3.0 | - | - | 0.9 | - | 0.9 | - | 0.9 |  |
|  |  |  | 4.5 | - | - | 1.35 | - | 1.35 | - | 1.35 |  |
|  |  |  | 5.5 | - | - | 1.65 | - | 1.65 | - | 1.65 |  |
| $\mathrm{V}_{\mathrm{OH}}$ | High-Level Output Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{IH}} \text { or } \mathrm{V}_{\mathrm{IL}} \\ & \mathrm{I}_{\mathrm{OH}}=-50 \mu \mathrm{~A} \\ & \mathrm{I}_{\mathrm{OH}}=-50 \mu \mathrm{~A} \\ & \mathrm{I}_{\mathrm{OH}}=-50 \mu \mathrm{~A} \\ & \mathrm{I}_{\mathrm{OH}}=-4 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{OH}}=-8 \mathrm{~mA} \end{aligned}$ | $\begin{aligned} & 2.0 \\ & 3.0 \\ & 4.5 \\ & 3.0 \\ & 4.5 \end{aligned}$ | $\begin{gathered} 1.9 \\ 2.9 \\ 4.4 \\ 2.58 \\ 3.94 \end{gathered}$ | $\begin{gathered} 2.0 \\ 3.0 \\ 4.5 \\ - \\ - \end{gathered}$ | - - - - | $\begin{aligned} & 1.9 \\ & 2.9 \\ & 4.4 \\ & 2.48 \\ & 3.80 \end{aligned}$ | - - - - | $\begin{aligned} & 1.9 \\ & 2.9 \\ & 4.4 \\ & 2.34 \\ & 3.66 \end{aligned}$ | $\begin{aligned} & - \\ & - \\ & - \\ & - \end{aligned}$ | V |
| V ${ }_{\text {OL }}$ | Low-Level Output Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{IH}} \text { or } \mathrm{V}_{\mathrm{IL}} \\ & \mathrm{IOL}_{\mathrm{OL}}=50 \mu \mathrm{~A} \\ & \mathrm{I}_{\mathrm{OL}}=50 \mu \mathrm{~A} \\ & \mathrm{IOL}^{2}=50 \mu \mathrm{AA} \\ & \mathrm{OL}=4 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{OL}}=8 \end{aligned}$ | $\begin{aligned} & 2.0 \\ & 3.0 \\ & 4.5 \\ & 3.0 \\ & 4.5 \end{aligned}$ | - - - - | $\begin{gathered} 0.0 \\ 0.0 \\ 0.0 \\ - \\ - \end{gathered}$ | $\begin{gathered} 0.1 \\ 0.1 \\ 0.1 \\ 0.36 \\ 0.36 \end{gathered}$ | - - - | $\begin{gathered} 0.1 \\ 0.1 \\ 0.1 \\ 0.44 \\ 0.44 \end{gathered}$ | $\begin{aligned} & - \\ & - \\ & - \\ & - \end{aligned}$ | $\begin{gathered} 0.1 \\ 0.1 \\ 0.1 \\ 0.52 \\ 0.52 \end{gathered}$ | V |
| $\mathrm{I}_{\mathrm{N}}$ | Input Leakage Current | $\begin{aligned} & \mathrm{V}_{\mathrm{IN}}=5.5 \mathrm{~V} \text { or } \\ & \mathrm{GND} \end{aligned}$ | $\begin{gathered} 2.0 \\ \text { to } 5.5 \end{gathered}$ | - | - | $\pm 0.1$ | - | $\pm 1.0$ | - | $\pm 1.0$ | $\mu \mathrm{A}$ |
| Ioz | 3-State Output Leakage Current | $\begin{aligned} & \mathrm{V}_{\text {OUT }}=0 \mathrm{~V} \text { to } \\ & 5.5 \mathrm{~V} \end{aligned}$ | 5.5 | - | - | $\pm 0.25$ | - | $\pm 2.5$ | - | $\pm 2.5$ | $\mu \mathrm{A}$ |
| IofF | Power Off Leakage Current | $\begin{aligned} & \mathrm{V}_{\text {IN }}=5.5 \mathrm{~V} \text { or } \\ & \mathrm{V}_{\text {OUT }}=5.5 \mathrm{~V} \end{aligned}$ | 0 | - | - | 1.0 | - | 10 | - | 10 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\mathrm{CC}}$ | Quiescent Supply Current | $\begin{aligned} & V_{I N}=V_{C C} \text { or } \\ & \text { GND } \end{aligned}$ | 5.5 | - | - | 1.0 | - | 20 | - | 40 | $\mu \mathrm{A}$ |

## MC74VHC1G125, MC74VHC1GT125

DC ELECTRICAL CHARACTERISTICS (MC74VHC1GT125)

| Symbol | Parameter | Test Conditions | $\mathrm{V}_{\mathrm{cc}}$ <br> (V) | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  |  | $-40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq 85^{\circ} \mathrm{C}$ |  | $-55^{\circ} \mathrm{C} \leq \mathrm{T}_{\text {A }} \leq 125^{\circ} \mathrm{C}$ |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | Min | Typ | Max | Min | Max | Min | Max |  |
| $\mathrm{V}_{\mathrm{IH}}$ | High-Level Input Voltage |  | 2.0 | 1.0 | - | - | 1.0 | - | 1.0 | - | V |
|  |  |  | 3.0 | 1.4 | - | - | 1.4 | - | 1.4 | - |  |
|  |  |  | 4.5 | 2.0 | - | - | 2.0 | - | 2.0 | - |  |
|  |  |  | 5.5 | 2.0 | - | - | 2.0 | - | 2.0 | - |  |
| $\mathrm{V}_{\text {IL }}$ | Low-Level Input Voltage |  | 2.0 | - | - | 0.28 | - | 0.28 | - | 0.28 | V |
|  |  |  | 3.0 | - | - | 0.45 | - | 0.45 | - | 0.45 |  |
|  |  |  | 4.5 | - | - | 0.8 | - | 0.8 | - | 0.8 |  |
|  |  |  | 5.5 | - | - | 0.8 | - | 0.8 | - | 0.8 |  |
| $\mathrm{V}_{\mathrm{OH}}$ | High-Level Output Voltage | $\begin{array}{\|l} \hline \mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{IH}} \text { or } \mathrm{V}_{\mathrm{IL}} \\ \mathrm{I}_{\mathrm{OH}}=-50 \mu \mathrm{~A} \\ \mathrm{I}_{\mathrm{OH}}=-50 \mu \mathrm{~A} \\ \mathrm{I}_{\mathrm{OH}}=-50 \mu \mathrm{~A} \\ \mathrm{I}_{\mathrm{OH}}=-4 \mathrm{~mA} \\ \mathrm{I}_{\mathrm{OH}}=-8 \mathrm{~mA} \\ \hline \end{array}$ | $\begin{aligned} & 2.0 \\ & 3.0 \\ & 4.5 \\ & 3.0 \\ & 4.5 \end{aligned}$ | $\begin{gathered} 1.9 \\ 2.9 \\ 4.4 \\ 2.58 \\ 3.94 \end{gathered}$ | $\begin{gathered} 2.0 \\ 3.0 \\ 4.5 \\ - \\ - \end{gathered}$ | - <br> - <br> - | $\begin{gathered} 1.9 \\ 2.9 \\ 4.4 \\ 2.48 \\ 3.80 \end{gathered}$ | $\begin{aligned} & - \\ & \text { - } \end{aligned}$ | $\begin{gathered} 1.9 \\ 2.9 \\ 4.4 \\ 2.34 \\ 3.66 \end{gathered}$ |  | V |
| $\mathrm{V}_{\text {OL }}$ | Low-Level Output Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{IH}} \text { or } \mathrm{V}_{\mathrm{IL}} \\ & \mathrm{I}_{\mathrm{IL}}=50 \mu \mathrm{~A} \\ & \mathrm{I}_{\mathrm{OL}}=50 \mu \mathrm{~A} \\ & \mathrm{I}_{\mathrm{OL}}=50 \mu \mathrm{~A} \\ & \mathrm{l}_{\mathrm{OL}}=4 \mathrm{~mA} \\ & \mathrm{I}_{\mathrm{OL}}=8 \mathrm{~mA} \end{aligned}$ | $\begin{aligned} & 2.0 \\ & 3.0 \\ & 4.5 \\ & 3.0 \\ & 4.5 \end{aligned}$ |  | $\begin{gathered} 0.0 \\ 0.0 \\ 0.0 \\ - \\ - \end{gathered}$ | $\begin{aligned} & 0.1 \\ & 0.1 \\ & 0.1 \\ & 0.36 \\ & 0.36 \end{aligned}$ |  | $\begin{gathered} 0.1 \\ 0.1 \\ 0.1 \\ 0.44 \\ 0.44 \end{gathered}$ |  | $\begin{gathered} 0.1 \\ 0.1 \\ 0.1 \\ 0.52 \\ 0.52 \end{gathered}$ | V |
| 1 N | Input Leakage Current | $\begin{aligned} & \mathrm{V}_{\text {IN }}=5.5 \mathrm{~V} \text { or } \\ & \text { GND } \end{aligned}$ | $\begin{gathered} 2.0 \\ \text { to } 5.5 \end{gathered}$ | - | - | $\pm 0.1$ | - | $\pm 1.0$ | - | $\pm 1.0$ | $\mu \mathrm{A}$ |
| loz | 3-State Output Leakage Current | $\begin{aligned} & \mathrm{V}_{\text {OUT }}=0 \mathrm{~V} \text { to } \\ & 5.5 \mathrm{~V} \end{aligned}$ | 5.5 | - | - | $\pm 0.25$ | - | $\pm 2.5$ | - | $\pm 2.5$ | $\mu \mathrm{A}$ |
| IofF | Power Off Leakage Current | $\begin{aligned} & \mathrm{V}_{\text {IN }}=5.5 \mathrm{~V} \text { or } \\ & \mathrm{V}_{\text {OUT }}=5.5 \mathrm{~V} \end{aligned}$ | 0 | - | - | 1.0 | - | 10 | - | 10 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\mathrm{CC}}$ | Quiescent Supply Current | $\begin{aligned} & \mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{CC}} \text { or } \\ & \text { GND } \end{aligned}$ | 5.5 | - | - | 1.0 | - | 20 | - | 40 | $\mu \mathrm{A}$ |
| ${ }^{\text {CCCT }}$ | Increase in Quiescent Supply Current per Input Pin | One Input: $\mathrm{V}_{\text {IN }}$ $=3.4 \mathrm{~V}$; Other Input at $\mathrm{V}_{\mathrm{CC}}$ or GND | 5.5 | - | - | 1.35 | - | 1.5 | - | 1.65 | mA |

## MC74VHC1G125, MC74VHC1GT125

AC ELECTRICAL CHARACTERISTICS

| Symbol | Parameter | Conditions | $\mathrm{V}_{\mathrm{cc}}(\mathrm{V})$ | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  |  | $-40^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq 85^{\circ} \mathrm{C}$ |  | $-55^{\circ} \mathrm{C} \leq \mathrm{T}_{\mathrm{A}} \leq 125^{\circ} \mathrm{C}$ |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | Min | Typ | Max | Min | Max | Min | Max |  |
| $\begin{aligned} & \hline \mathrm{t}_{\mathrm{PLL}}, \\ & \mathrm{t}_{\mathrm{PH}}, \end{aligned}$ | Propagation Delay, $A$ to $Y$ <br> (Figures 3 and 4) | $\mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$ | 3.0 to 3.6 | - | 4.5 | 8.0 | - | 9.5 | - | 12.0 | ns |
|  |  | $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ |  | - | 6.4 | 11.5 | - | 13.0 | - | 16.0 |  |
|  |  | $\mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$ | 4.5 to 5.5 | - | 3.5 | 5.5 | - | 6.5 | - | 8.5 |  |
|  |  | $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ |  | - | 4.5 | 7.5 | - | 8.5 | - | 10.5 |  |
| $\begin{aligned} & \text { tpZL, } \\ & \mathrm{t}_{\text {PZH }} \end{aligned}$ | Output Enable Time, $\overline{O E}$ to $Y$ (Figures 3 and 4) | $\mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$ | 3.0 to 3.6 | - | 4.5 | 8.0 | - | 9.5 | - | 11.5 | ns |
|  |  | $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ |  | - | 6.4 | 11.5 | - | 13.0 | - | 15.0 |  |
|  |  | $\mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$ | 4.5 to 5.5 | - | 3.5 | 5.1 | - | 6.0 | - | 8.5 |  |
|  |  | $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ |  | - | 4.5 | 7.1 | - | 8.0 | - | 10.5 |  |
| $\begin{aligned} & \text { tpLZ, } \\ & \mathrm{t}_{\mathrm{PH}} \end{aligned}$ | Output Disable Time, $\overline{O E}$ to $Y$ (Figures 3 and 4) | $\mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$ | 3.0 to 3.6 | - | 6.5 | 9.7 | - | 11.5 | - | 14.5 | ns |
|  |  | $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ |  | - | 8.0 | 13.2 | - | 15.0 | - | 18.0 |  |
|  |  | $\mathrm{C}_{\mathrm{L}}=15 \mathrm{pF}$ | 4.5 to 5.5 | - | 4.8 | 6.8 | - | 8.0 | - | 10.0 |  |
|  |  | $\mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}$ |  | - | 7.0 | 8.8 | - | 10.0 | - | 12.0 |  |
| $\mathrm{C}_{\text {IN }}$ | Input Capacitance |  |  | - | 4.0 | 10 | - | 10 | - | 10 | pF |
| $\mathrm{C}_{\text {OUT }}$ | Output Capacitance | Output in High Impedance State |  | - | 6.0 | - | - | - | - | - | pF |


|  |  | Typical @ 25 ${ }^{\circ} \mathbf{C}, \mathbf{\mathbf { V } _ { \mathbf { C C } } = 5 . 0 \mathbf { V }}$ |  |
| :--- | :--- | :---: | :---: |
| C | pF |  |  |

5. $C_{P D}$ is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: $\mathrm{I}_{\mathrm{CC}(\mathrm{OPR})}=\mathrm{C}_{\mathrm{PD}} \bullet \mathrm{V}_{\mathrm{CC}} \bullet \mathrm{f}_{\mathrm{in}}+\mathrm{I}_{\mathrm{CC}}$. $\mathrm{C}_{\mathrm{PD}}$ is used to determine the no-load dynamic power consumption; $\mathrm{P}_{\mathrm{D}}=\mathrm{C}_{\mathrm{PD}} \bullet \mathrm{V}_{\mathrm{CC}}{ }^{2} \bullet \mathrm{f}_{\mathrm{in}}+\mathrm{I}_{\mathrm{CC}} \bullet \mathrm{V}_{\mathrm{CC}}$.

## MC74VHC1G125, MC74VHC1GT125



| Test | Switch Position | $C_{L}, \mathrm{pF}$ | RL, $\boldsymbol{\Omega}$ |
| :---: | :---: | :---: | :---: |
| $\mathrm{t}_{\text {PLH }} / \mathrm{t}_{\text {PHL }}$ | Open | See AC Characteristics Table | X |
| $\mathrm{t}_{\text {PLZ }} / \mathrm{t}_{\text {PZL }}$ | $V_{\text {CC }}$ |  | 1 k |
| $\mathrm{t}_{\text {PHZ }} / \mathrm{t}_{\text {PZH }}$ | GND |  | 1 k |

X = Don't Care
$\mathrm{C}_{\mathrm{L}}$ includes probe and jig capacitance
$\mathrm{R}_{\mathrm{T}}$ is $\mathrm{Z}_{\mathrm{OUT}}$ of pulse generator (typically $50 \Omega$ )
$\mathrm{f}=1 \mathrm{MHz}$
Figure 3. Test Circuit


Figure 4. Switching Waveforms

| $\mathbf{v}_{\mathbf{C C}}, \mathbf{v}$ | $\mathbf{V}_{\mathbf{m o}}, \mathbf{V}$ |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  |  |  | $\mathbf{t}_{\mathbf{P Z L}}, \mathbf{t}_{\mathbf{P L Z}}, \mathbf{t}_{\mathbf{P Z H}}, \mathbf{t}_{\mathbf{P H Z}}$ | $\mathbf{v}_{\mathbf{Y},} \mathbf{v}$ |
|  | $\mathrm{~V}_{\mathrm{CC}} / 2$ | $\mathrm{~V}_{\mathrm{CC}} / 2$ | $\mathrm{~V}_{\mathrm{CC}} / 2$ | 0.3 |
| 4.5 to 5.5 | $\mathrm{~V}_{\mathrm{CC}} / 2$ | $\mathrm{~V}_{\mathrm{CC}} / 2$ | $\mathrm{~V}_{\mathrm{CC}} / 2$ | 0.3 |

## MC74VHC1G125, MC74VHC1GT125

ORDERING INFORMATION

| Device | Packages | Specific Device Code | Pin 1 Orientation (See below) | Shipping ${ }^{\dagger}$ |
| :---: | :---: | :---: | :---: | :---: |
| M74VHC1G125DFT1G | SC-88A | W0 | Q2 | 3000 / Tape \& Reel |
| M74VHC1G125DFT2G | SC-88A | W0 | Q4 | 3000 / Tape \& Reel |
| NLVVHC1G125DFT1G* | SC-88A | W0 | Q2 | 3000 / Tape \& Reel |
| M74VHC1GT125DF1G | SC-88A | W1 | Q2 | 3000 / Tape \& Reel |
| M74VHC1GT125DF2G | SC-88A | W1 | Q4 | 3000 / Tape \& Reel |
| NLVVHC1GT125DF1G* | SC-88A | W1 | Q2 | 3000 / Tape \& Reel |
| NLVVHC1GT125DF2G* | SC-88A | W1 | Q4 | 3000 / Tape \& Reel |
| MC74VHC1G125DBVT1G | SC-74A | W0 | Q4 | 3000 / Tape \& Reel |
| MC74VHC1GT125DBVT1G | SC-74A | W1 | Q4 | 3000 / Tape \& Reel |
| M74VHC1G125DTT1G | TSOP-5 | W0 | Q4 | 3000 / Tape \& Reel |
| M74VHC1GT125DT1G | TSOP-5 | W1 | Q4 | 3000 / Tape \& Reel |
| NLVVHC1GT125DT1G* | TSOP-5 | W1R | Q4 | 3000 / Tape \& Reel |
| MC74VHC1G125P5T5G | SOT-953 | T | Q2 | 8000 / Tape \& Reel |
| MC74VHC1GT125P5T5G (In Development) | SOT-953 | TBD | Q2 | 8000 / Tape \& Reel |
| MC74VHC1G125MU1TCG (In Development) | UDFN6, $1.45 \times 1.0,0.5 \mathrm{P}$ | TBD | Q4 | 3000 / Tape \& Reel |
| MC74VHC1GT125MU1TCG | UDFN6, $1.45 \times 1.0,0.5 \mathrm{P}$ | D | Q4 | 3000 / Tape \& Reel |
| MC74VHC1GT125MU2TCG | UDFN6, $1.2 \times 1.0,0.4 \mathrm{P}$ | 7 | Q4 | 3000 / Tape \& Reel |
| MC74VHC1G125MU3TCG (In Development) | UDFN6, $1.0 \times 1.0,0.35 \mathrm{P}$ | TBD | Q4 | 3000 / Tape \& Reel |
| MC74VHC1GT125MU3TCG | UDFN6, $1.0 \times 1.0,0.35 \mathrm{P}$ | L | Q4 | 3000 / Tape \& Reel |

$\dagger$ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

Pin 1 Orientation in Tape and Reel
Direction of Feed



SCALE 2:1


1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS A AND B DO NOT INCLUDE MOLD
FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE

| DIM | MILLIMETERS |  |
| :---: | :---: | :---: |
|  | MIN | MAX |
| A | 0.90 | 1.10 |
| A1 | 0.01 | 0.10 |
| $\mathbf{b}$ | 0.25 | 0.50 |
| $\mathbf{c}$ | 0.10 | 0.26 |
| $\mathbf{D}$ | 2.85 | 3.15 |
| E | 2.50 | 3.00 |
| E1 | 1.35 | 1.65 |
| $\mathbf{e}$ | 0.95 BSC |  |
| $\mathbf{L}$ | 0.20 | 0.60 |
| $\mathbf{M}$ | $0^{\circ}$ |  |

RECOMMENDED SOLDERING FOOTPRINT*


GENERIC MARKING DIAGRAM*


XXX = Specific Device Code
$M \quad=$ Date Code

- $\quad=$ Pb-Free Package
(Note: Microdot may be in either location)
*This information is generic. Please refer to device data sheet for actual part marking. $\mathrm{Pb}-$ Free indicator, " G " or microdot " - ", may or may not be present. Some products may not follow the Generic Marking.
*For additional information on our $\mathrm{Pb}-$ Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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| DESCRIPTION: | SC-74A | PAGE 1 OF 1 |

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1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. 419A-01 OBSOLETE. NEW STANDARD 419A-02.
4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

| DIM | INCHES |  | MILLIMETERS |  |
| :---: | :---: | :---: | :---: | :---: |
|  | MIN | MAX | MIN | MAX |
| A | 0.071 | 0.087 | 1.80 | 2.20 |
| B | 0.045 | 0.053 | 1.15 | 1.35 |
| C | 0.031 | 0.043 | 0.80 | 1.10 |
| D | 0.004 | 0.012 | 0.10 |  |
| G | 0.026 BSC |  | 0.65 |  |


(Note: Microdot may be in either location)
*This information is generic. Please refer to device data sheet for actual part marking. $\mathrm{Pb}-F r e e$ indicator, " G " or microdot " $\mathrm{=}$ ", may or may not be present. Some products may not follow the Generic Marking.

```
```

STYLE 1:

```
```

STYLE 1:
STYLE 1:
STYLE 1:
2. EMITTER
2. EMITTER
3. BASE
3. BASE
4. COLLECTOR
4. COLLECTOR
5. COLLECTOR

```
```

        5. COLLECTOR
    ```
```

```
STYLE 2:
    PIN 1. ANODE
    2. EMITTER
    STYLE 3
```

STYLE 6:
PIN 1. EMITTER 2
2. BASE 2
3. EMITTER 1
4. COLLECTOR
5. COLLECTOR 2/BASE

STYLE 7:
PIN 1. BASE
2. EMITTER
3. BASE
4. COLLECTOR
5. COLLECTOR

STYLE 3
PIN 1. ANODE
2. N/C
3. ANODE 2
4. CATHODE 2
5. CATHODE

## STYLE 8

PIN 1. CATHODE
2. COLLECTOR
3. $\mathrm{N} / \mathrm{C}$
4. BASE
5. EMITTER

SOLDER FOOTPRINT


STYLE 4:
PIN 1. SOURCE 1
2. DRAIN $1 / 2$
3. SOURCE 1
4. GATE 1
5. GATE 2

STYLE 9:
PIN 1. ANODE
2. CATHODE
3. ANODE
4. ANODE
5. ANODE

## STYLE 5:

PIN 1. CATHODE
2. COMMON ANODE
3. CATHODE 2
4. CATHODE 3
5. CATHODE 4

Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

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| ---: | :--- | :--- | :--- |
| DESCRIPTION: | SC-88A (SC-70-5/SOT-353) | PAGE 1 OF 1 |

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TSOP-5
CASE 483
ISSUE N
DATE 12 AUG 2020
SCALE 2:1
 Mounting Techniques Reference Manual, SOLDERRM/D.

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| DESCRIPTION: | TSOP-5 | PAGE 1 OF 1 |

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UDFN6, 1.2x1.0, 0.4P
CASE 517AA-01
ISSUE D
DATE 03 SEP 2010

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 mm FROM TERMINAL
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

|  | MILLIMETERS |  |
| :---: | :---: | :---: |
| DIM | MIN | MAX |
| A | 0.45 | 0.55 |
| A1 | 0.00 | 0.05 |
| A3 | 0.127 |  |
| REF |  |  |
| b | 0.15 |  |
| D | 1.20 |  |
| BSC |  |  |
| E | 1.00 |  |
| BSC |  |  |
| e | 0.40 |  |
| BSC |  |  |
| L | 0.30 | 0.40 |
| L1 | 0.00 | 0.15 |
| L2 | 0.40 | 0.50 |

Side View (Optional)

GENERIC
MARKING DIAGRAM*


X = Specific Device Code
M = Date Code
*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, " G " or microdot " $\mathrm{\bullet}$ ", may or may not be present.

## MOUNTING FOOTPRINT*


*For additional information on our Pb -Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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| DESCRIPTION: | 6 PIN UDFN, 1.2X1.0, 0.4P | PAGE 1 OF 1 |

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UDFN6, 1.45x1.0, 0.5P CASE 517AQ

ISSUE O
DATE 15 MAY 2008


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
CONTROLLING DIMENSION: MILLIMETERS
2. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 mm FROM THE TERMINAL TIP.


DETAIL B OPTIONAL CONSTRUCTIONS

## MOUNTING FOOTPRINT



DIMENSIONS: MILLIMETERS
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## GENERIC

MARKING DIAGRAM*


X = Specific Device Code
M = Date Code
*This information is generic. Please refer to device data sheet for actual part marking. $\mathrm{Pb}-$ Free indicator, "G" or microdot " $\quad$ ", may or may not be present.

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| ---: | :--- | :--- | :--- |
| DESCRIPTION: | UDFN6, 1.45x1.0, 0.5P | PAGE 1 OF 1 |

[^0]UDFN6, 1x1, 0.35P
CASE 517BX
ISSUE O
DATE 18 MAY 2011

*For additional information on our $\mathrm{Pb}-$ Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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| ---: | :--- | :--- | :--- |
| DESCRIPTION: | UDFN6, 1x1, 0.35P |  | PAGE 1 OF 1 |

[^1]SCALE 4:1

*For additional information on our $\mathrm{Pb}-$ Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME

Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

|  | MILLIMETERS |  |  |
| :---: | :---: | :---: | :---: |
| DIM | MIN | NOM | MAX |
| A | 0.34 | 0.37 | 0.40 |
| b | 0.10 | 0.15 | 0.20 |
| C | 0.07 | 0.12 | 0.17 |
| D | 0.95 | 1.00 | 1.05 |
| E | 0.75 | 0.80 | 0.85 |
| e | 0.35 BSC |  |  |
| HE $^{2}$ | 0.95 | 1.00 | 1.05 |
| L | 0.175 REF |  |  |
| L2 | 0.05 | 0.10 | 0.15 |
| L3 | --- | --- | 0.15 |

GENERIC MARKING DIAGRAM*


X = Specific Device Code
M = Month Code
*This information is generic. Please refer to device data sheet for actual part marking.
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| DESCRIPTION: | SOT-953 | PAGE 1 OF 1 |

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